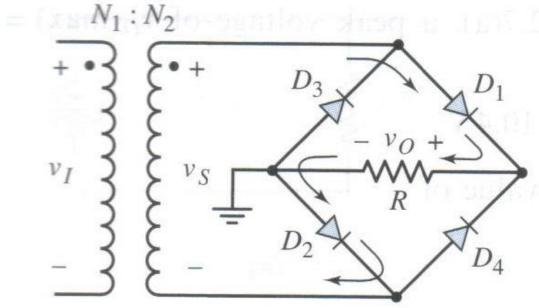
Bridge Rectifier

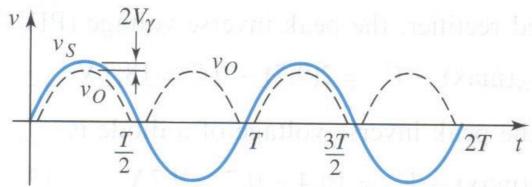
Semiconductor Devices and Circuits (ECE 181302)

23rd November 2021

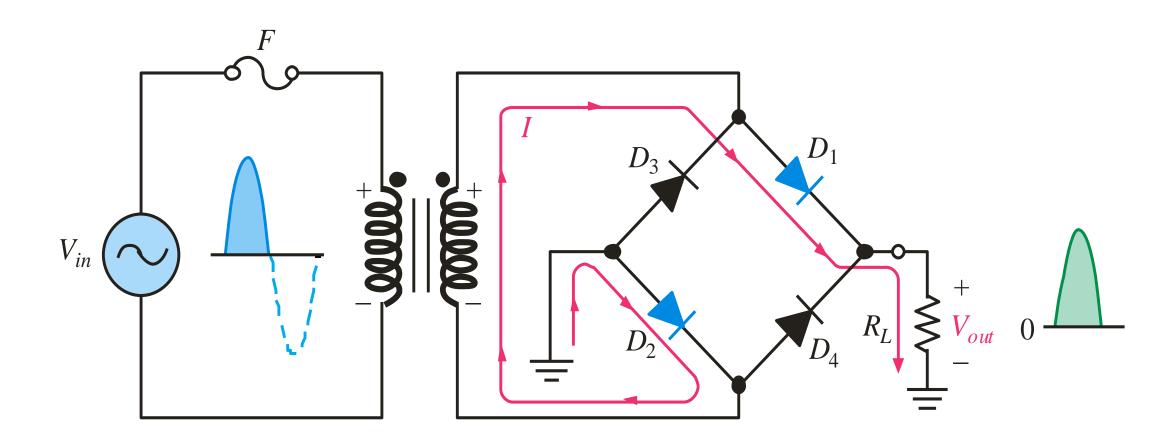
Bridge Rectifier

Positive cycle, D_1 and D_2 conducts, D_3 and D_4 off; + $\nabla \gamma + \nabla 0 + \nabla \gamma - \nabla s = 0$ Vo = $\nabla s - 2\nabla \gamma$





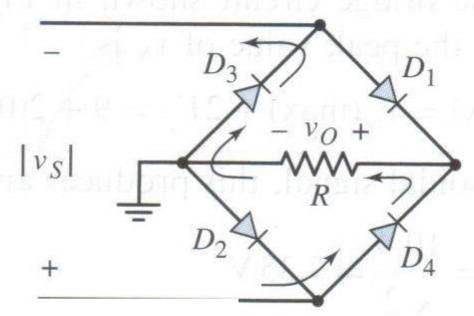
How the conduction path for the positive halfcycle looks like:

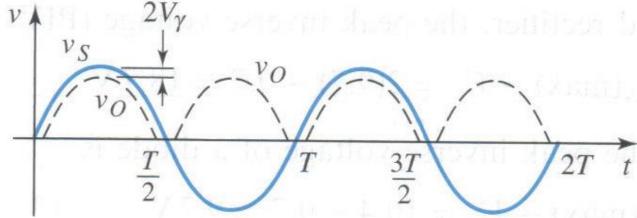


Negative cycle, D3 and D4 conducts, D1 and D2 off

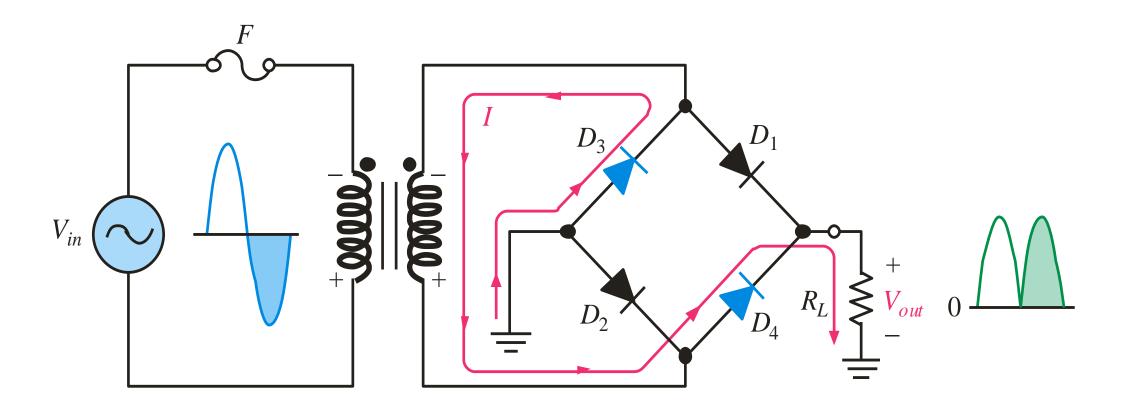
+
$$V\gamma$$
 + Vo + $V\gamma$ - Vs = 0

$$Vo = Vs - 2V\gamma$$

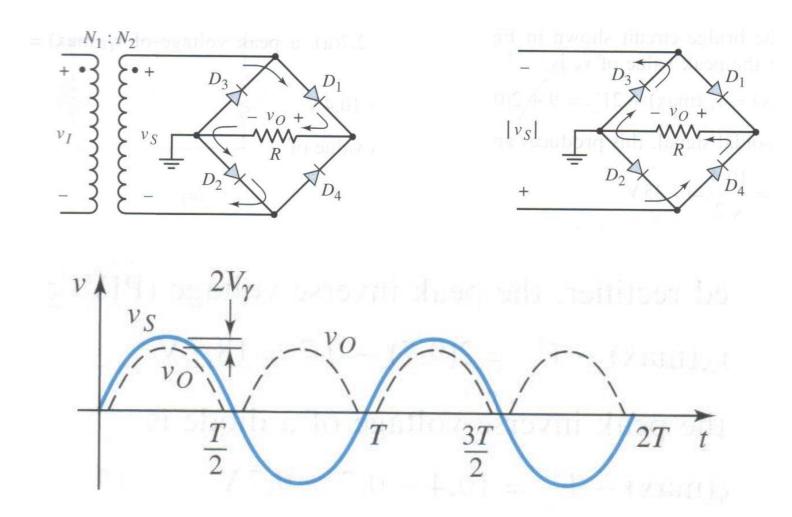




How the conduction path for the negative halfcycle looks like:



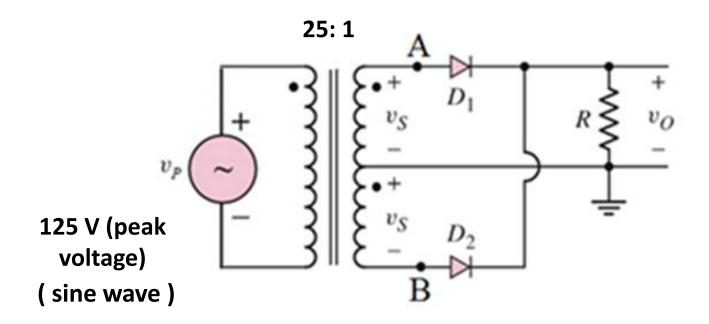
Full-Wave Rectification:

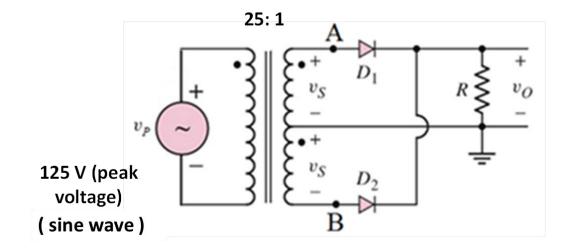


> Also notice that the **polarity of the output voltage for both cycles is the same**

Example:

- Assume that for each diode, the cut-in voltage, V_{γ} = 0.6V and the diode forward resistance, r_f is 15 Ω . The load resistor, R = 95 Ω . Determine:
 - The peak output voltage, V_o across the load, R
 - Sketch the output voltage, V_o and label its peak value.





• **SOLUTION**

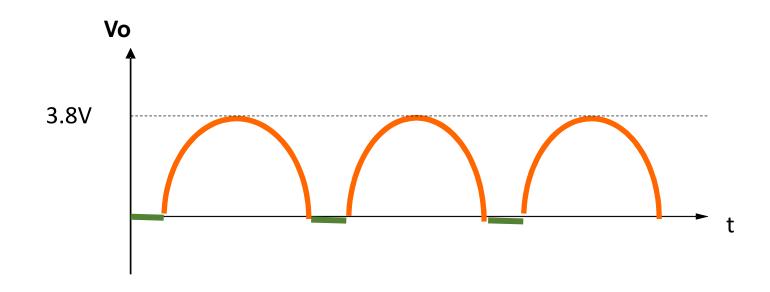
• peak output voltage, V_o

$$V_{s (peak)} = 125 / 25 = 5V$$

 $V_{\gamma} + I_{D}(15) + I_{D}(95) - V_{s(peak)} = 0$

$$I_D = (5 - 0.6) / 110 = 0.04 A$$

 $V_{o (peak)} = 95 \times 0.04 = 3.8V$



DC Voltage and RMS Voltage: Centre Tapped

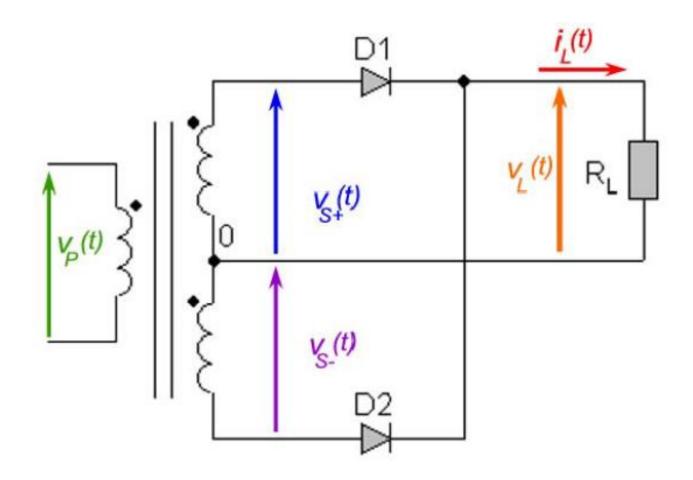
• Average value/DC value/mean value = $\frac{Area\ over\ one\ period}{Total\ time\ period}$

$$V_{\rm DC} = \frac{1}{T} \int_0^T v_{\rm L}(t) dt = \frac{2}{2\pi} \int_0^{\pi} V_{\rm S} \sin(\varpi t) dt = \frac{2 \cdot V_{\rm S}}{\pi}$$

$$V_{DC}$$
= 0.636 V_S = 2 x 0.318 V_S

$$V_{rms} = \sqrt{\frac{1}{T} \int_{0}^{T} v_{L}^{2}(t) dt} = \sqrt{\frac{1}{\pi} \int_{0}^{\pi} V_{S}^{2} \sin^{2}(\varpi t) dt} = \frac{V_{S}}{\sqrt{2}}$$

Structure of Full Wave Rectifier: Centre Tapped



$$I_{\rm DC} = \frac{V_{\rm DC}}{R_{\rm L}} = \frac{2 \cdot V_{\rm S}}{\pi \cdot R_{\rm L}}$$

$$I_{\text{DC}} = \frac{V_{\text{DC}}}{R_{\text{L}}} = \frac{2 \cdot V_{\text{S}}}{\pi \cdot R_{\text{L}}} \qquad I_{rms} = \frac{V_{rms}}{R_{\text{L}}} = \frac{V_{\text{S}}}{\sqrt{2} \cdot R_{\text{L}}}$$

$$FF = \frac{V_{rms}}{V_{DC}} = \frac{\pi}{2 \cdot \sqrt{2}} = 1.11$$

$$\eta = \left(\frac{1}{FF}\right)^2 = 0.81$$
 $RF = \sqrt{FF^2 - 1} = 0.483$.

$$RF = \sqrt{FF^2 - 1} = 0.483$$

PIV

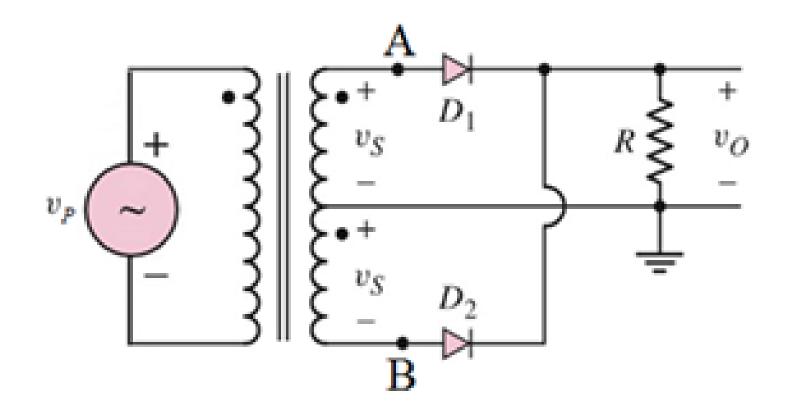
The **peak inverse voltage (PIV)** of the diode is the peak value of the voltage that a diode can withstand when it is reversed biased

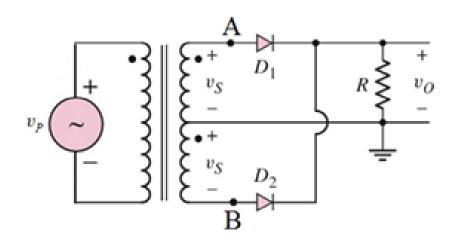
Type of Rectifier	PIV
Half Wave	Peak value of the input secondary voltage, V _{s (peak)}
Full Wave : Center- Tapped	$2V_{s(peak)}$ - V_{γ}
Full Wave: Bridge	$V_{s(peak)}$ - V_{γ}

Example:

- Calculate the transformer turns ratio and the PIV voltages for each type of the full wave rectifier
 - a) center-tapped
 - b) bridge

• Assume the input voltage of the transformer is 220 V (rms), 50 Hz from ac main line source. The desired peak output voltage is 9 volt; also assume diodes cut-in voltage = 0.6 V.





$$\frac{v_p}{v_S} = \frac{N_1}{N_2}$$

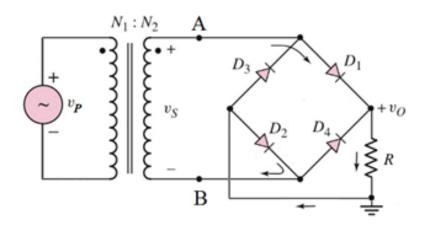
Solution: For the centre-tapped transformer circuit the peak voltage of the transformer secondary is required

The peak output voltage = 9V Output voltage, Vo = Vs - V γ Hence, Vs = 9 + 0.6 = 9.6V **Peak value = Vrms x** $\sqrt{2}$ So, Vs (rms) = 9.6 / $\sqrt{2}$ = 6.79 V

The turns ratio of the primary to each secondary winding is

$$\frac{N_1}{N_2} = \frac{220}{6.79} = 32.40$$

The PIV of each diode: $2V_{s(peak)} - V_{\gamma} = 2(9.6) - 0.6 = 19.6 - 0.6 = 18.6 \text{ V}$



Solution: For the bridge transformer circuit the peak voltage of the transformer secondary is required

The peak output voltage = 9V

Output voltage, Vo = Vs - $2V\gamma$

Hence, Vs = 9 + 1.2 = 10.2 V

Peak value = Vrms x $\sqrt{2}$

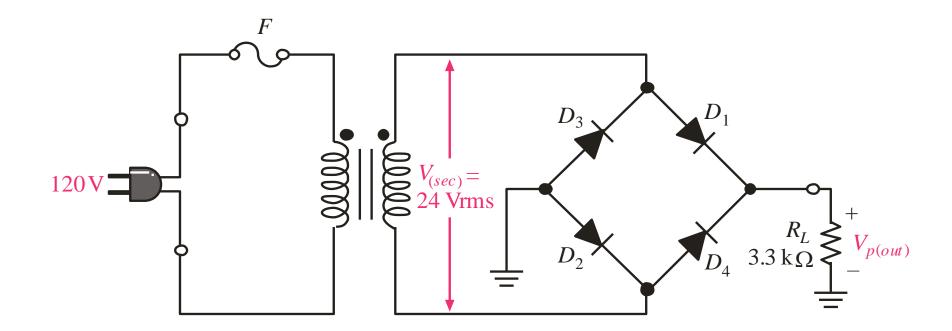
So, Vs (rms) = $10.2 / \sqrt{2} = 7.21 \text{ V}$

The turns ratio of the primary to each secondary winding is

The PIV of each diode: $V_{s(peak)}$ $V_{\gamma} = 10.2 - 0.6 = 9.6 V$

$$\frac{N_1}{N_2} = \frac{220}{7.21} = 30.5$$

Determine the peak output voltage and current in the 3.3 k Ω load resistor if V_{sec} = 24 V_{rms} . Use the practical diode model.



The peak output voltage is:

$$V_{p(sec)} = 1.41V_{rms} = 33.9 \text{ V}$$

$$V_{p(out)} = V_{p(sec)} - 1.4 \text{ V} = 32.5 \text{ V}$$

Applying Ohm's law,

$$I_{p(out)} = 9.8 \text{ mA}$$

Review: Full Wave Rectifiers

A full wave rectifier allows unidirectional current through the load during the entire 360 degree of input cycle.

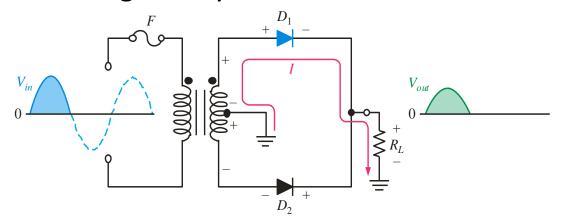


❖The output voltage have twice the input frequency.
VAVG = 2Vpeak / pi

❖ V_{AVG} is 63.7% of Vpeak

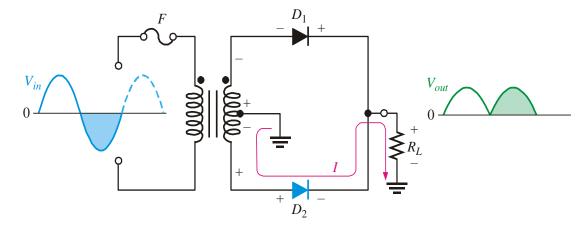
Recap: Center-Tapped Full Wave Rectifier

• A center-tapped transformer is used with two diodes that conduct on alternating half-cycles.



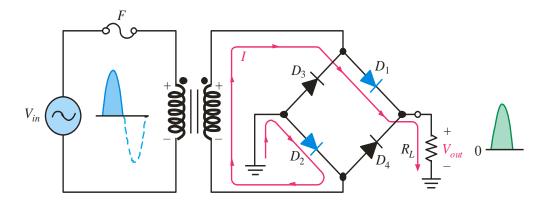
During the positive half-cycle, the upper diode is forward-biased and the lower diode is reversebiased.

During the negative half-cycle, the lower diode is forward-biased and the upper diode is reverse-biased.



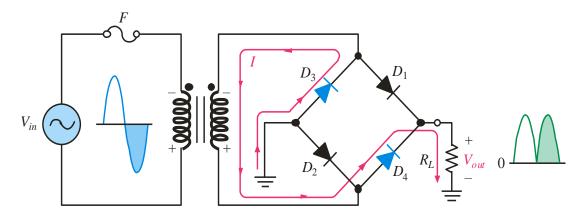
Recap: Bridge Full-Wave Rectifier

The Bridge Full-Wave rectifier uses four diodes connected across the entire secondary as shown.



Conduction path for the positive half-cycle.

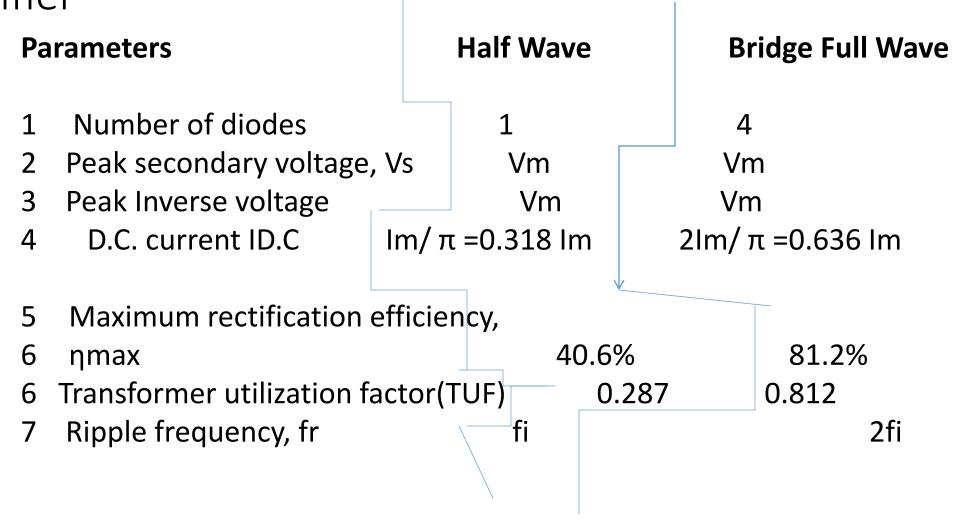
Conduction path for the negative half-cycle.



Advantages of Full-Wave Rectifier Over Half-Wave Rectifier

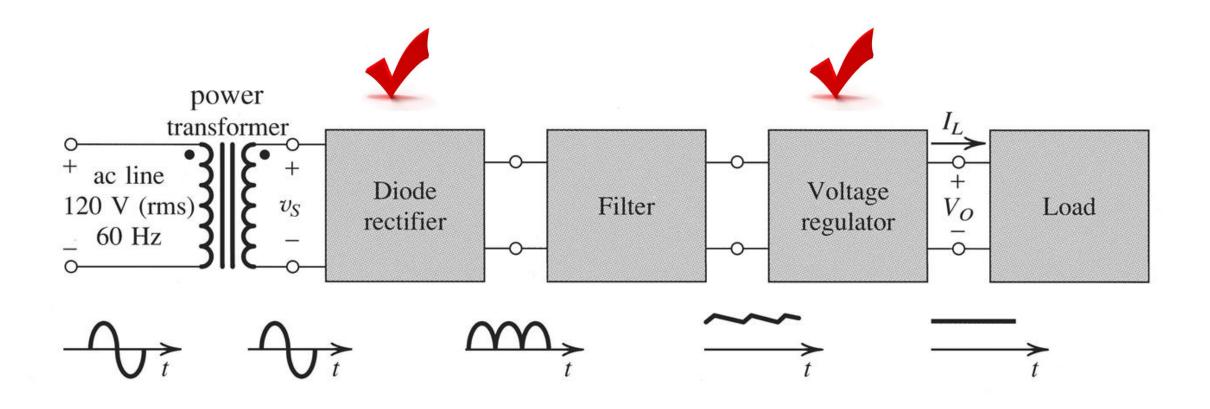
- The DC output voltage and load current values of full wave rectifier are twice than those of half wave rectifier.
- 2. The ripple factor is much less (0.482) than that of half wave rectifier (1.21).
- 3. The efficiency of full wave rectifier is twice (81.2%) than that of half wave rectifier (40.6%).
- 4. The TUF (Transformer Utilization Factor) of full wave rectifier is more than that of half wave rectifier.

Difference Between Half-Wave and Bridge Full-Wave Rectifier



Points to Note...

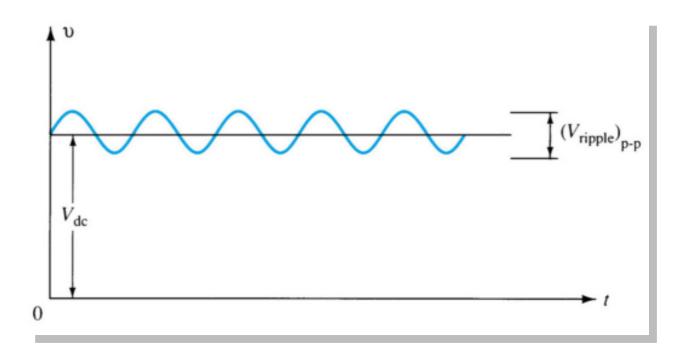
- The most important consideration in designing a power supply is the DC voltage at the output
- It should be able to furnish the maximum current needed, maintaining the voltage at a constant level
- The AC ripple should be low
- The power supply should be protect in the event of short circuit on the load side
- The response of the power supply to temperature changes should be minimum



- Ripples: The output from the rectifier section is a pulsating DC.
- Need the filter circuit to reduce the peak-to-peak pulses to a small ripple voltage.

Ripple Factor

After the filter circuit a small amount of AC is still remaining. The amount of ripple voltage can be rated in terms of ripple factor (r).



%r =
$$\frac{\text{ripple voltage (rms)}}{\text{dc voltage}} = \frac{V_{r(rms)}}{V_{dc}} \times 100$$

Ripple Factor: Comparison

Half-Wave

DC output:

$$V_{dc} = 0.318V_{m}$$

AC ripple output:

$$V_{r(rms)} = 0.385V_{m}$$

Ripple factor:

$$\%r = \frac{V_{r(rms)}}{V_{dc}} \times 100$$
$$= \frac{0.385V_{m}}{0.318V_{m}} \times 100 = 121\%$$

Full-Wave

DC output:

$$V_{dc} = 0.636V_{m}$$

AC ripple output:

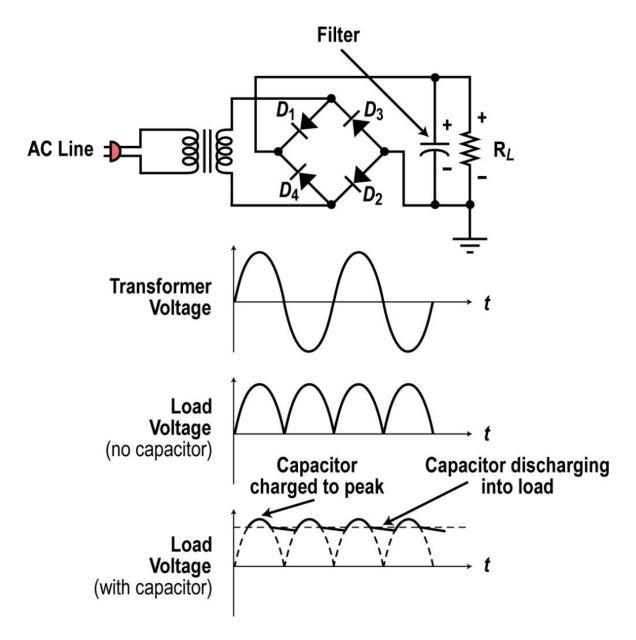
$$V_{r(rms)} = 0.308V_{m}$$

Ripple factor:

$$\%r = \frac{V_{r(rms)}}{V_{dc}} \times 100$$
$$= \frac{0.308_{Vm}}{0.636_{Vm}} \times 100 = 48\%$$

How the Filter Works

- A large <u>capacitor</u> is connected across the load resistor. This capacitor <u>filters the</u> pulses into a more constant DC.
- When the diode conducts, the capacitor charges up to the peak of the sine wave.
- Then when the sine voltage drops, the charge on the capacitor remains. Since the capacitor is large it forms a long time constant with the load resistor. The capacitor slowly discharges into the load maintaining a more constant output.
- The next positive pulse comes along recharging the capacitor and the process continues.



- The capacitor does a good job of smoothing the pulses from the rectifier into a more constant DC.
- A small variation occurs in the DC because the capacitor discharges a small amount between the positive and negative pulses. Then it recharges. This variation is called ripple.
- The ripple can be reduced further by making the capacitor larger.
- The ripple appears to be a sawtooth shaped AC variation riding on the DC output.
- A small amount of ripple can be tolerated in some circuits but the lower the better overall.



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